

Half Wavelength Contact Acoustic Microscopy (HaWaCAM): a novel metrology technique for semicon

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I. Introduction

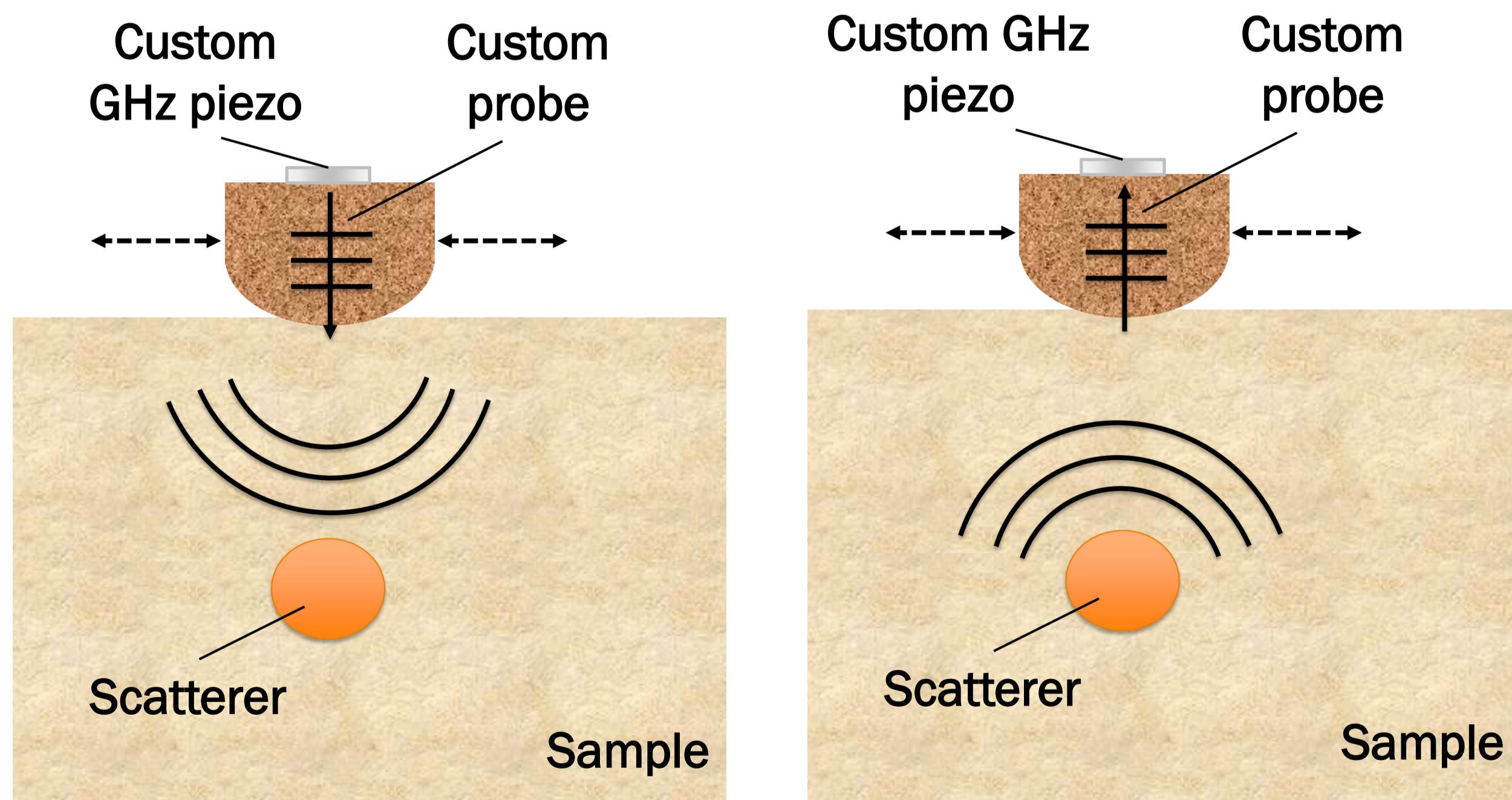
- Ever more functionality and processing power is integrated on the same semiconductor area.
 - To do so the device structures have become 3D,
 - and 3D NAND stack heights keep increasing.
- Cost effective device fabrication at high throughput requires metrology.
- The current non-destructive metrology workhorse for semicon is optics based.
- Optical metrology typically features 0.2 – 1.5 μm resolution and is limited by:
 1. optically opaque layers,
 2. a low penetration depth ($O(1 \mu\text{m})$).
- Acoustic microscopy may solve these limitations.
- However, its resolution is limited $> O(3 \text{ (PMMA)} - 6 \text{ (SiO}_2\text{) } \mu\text{m}$ in samples
- Acoustic microscopy uses a geometric lens and a coupling liquid to couple the acoustic waves into the sample and to enable good lateral resolution [1].
- Acoustic frequency (resolution) limited by attenuation in coupling layer

GOAL:

- To present a novel high frequency acoustic metrology technique entitled Half-Wavelength Contact Acoustic Microscopy (HaWaCAM), which does not require a liquid coupling layer.

II. HaWaCAM measurement concept

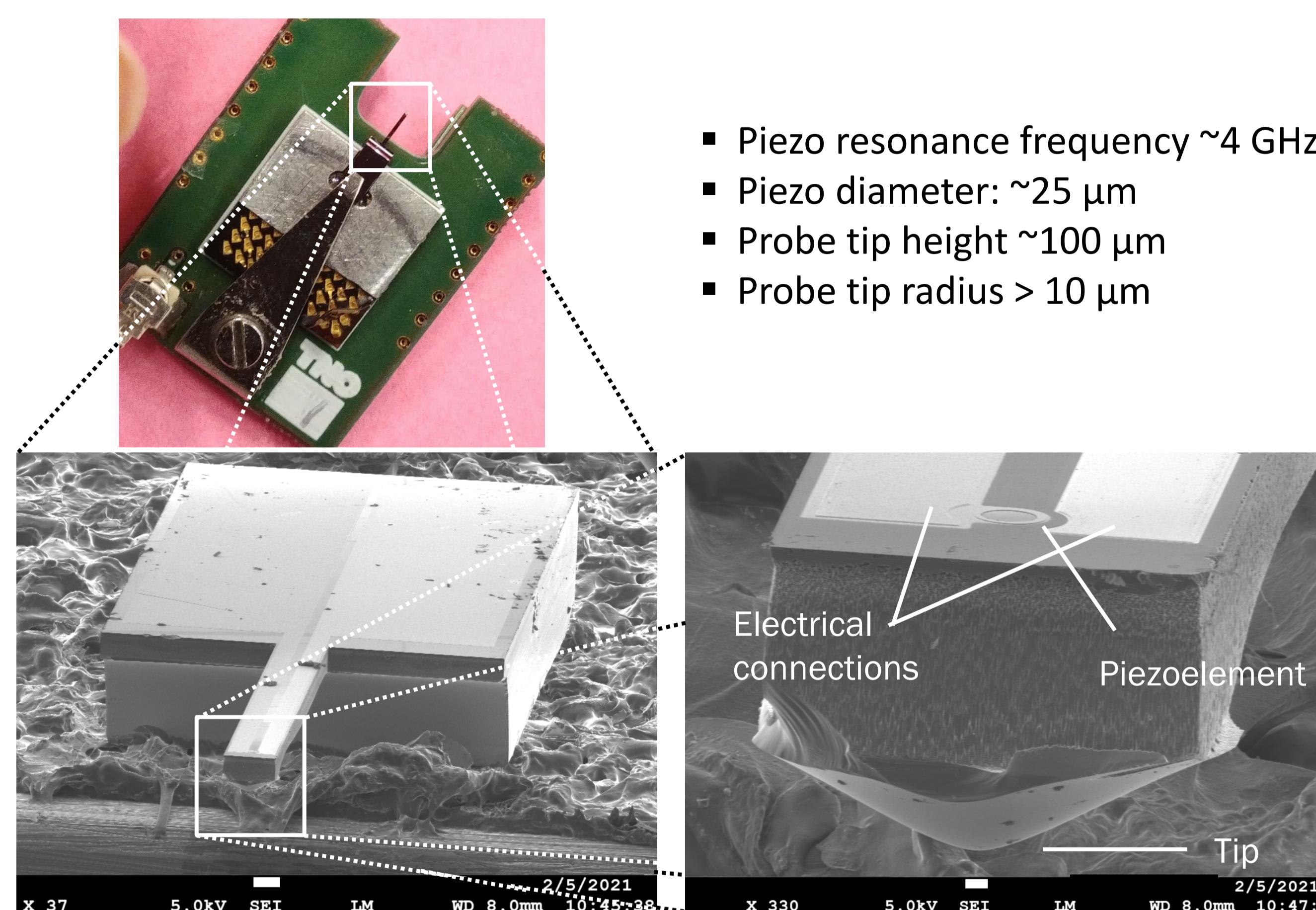
- HaWaCAM marries a probe with GHz piezotransducers
- Image contrast depends on acoustic impedance differences
- Tip – sample contact diameter \sim half wavelength
- Tip – sample contact: linear



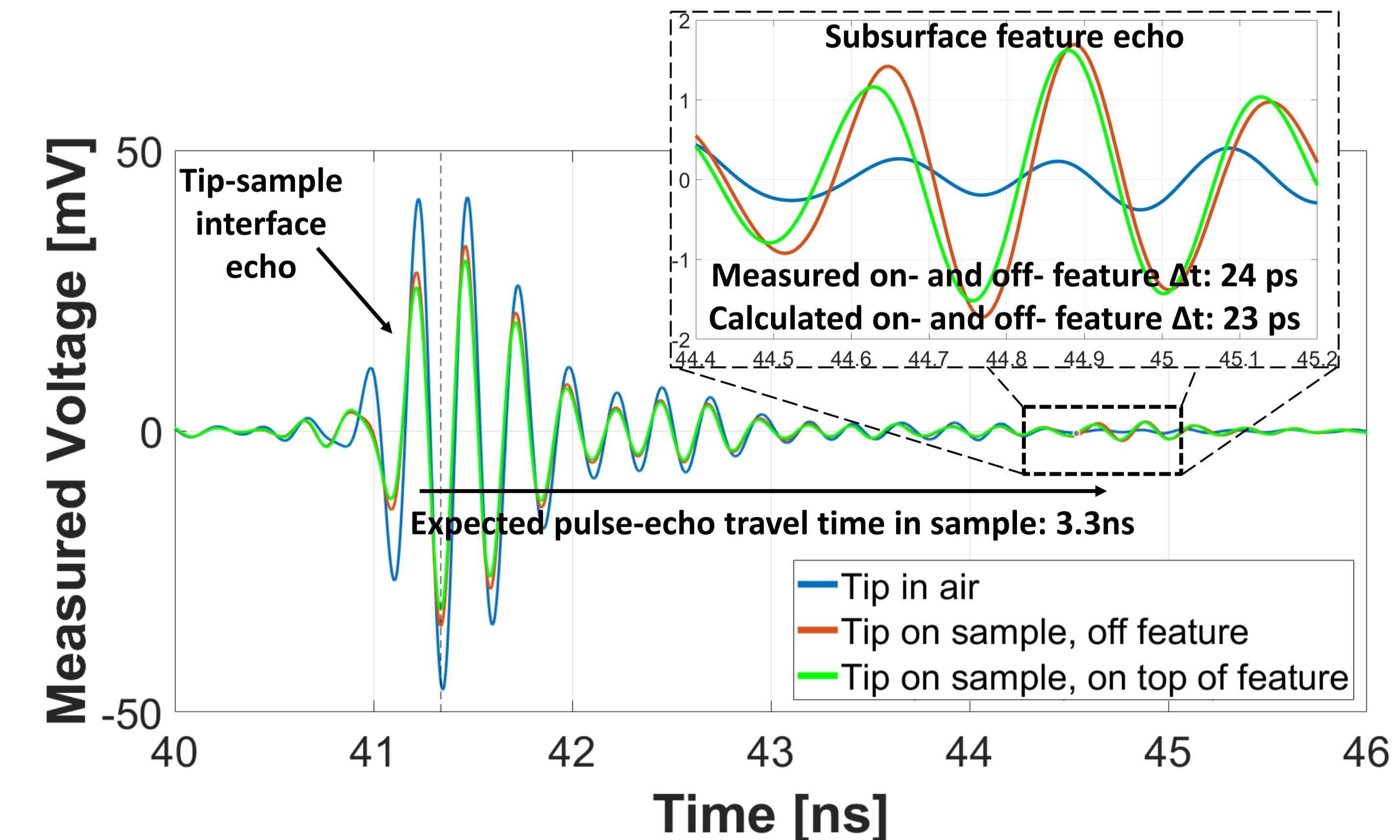
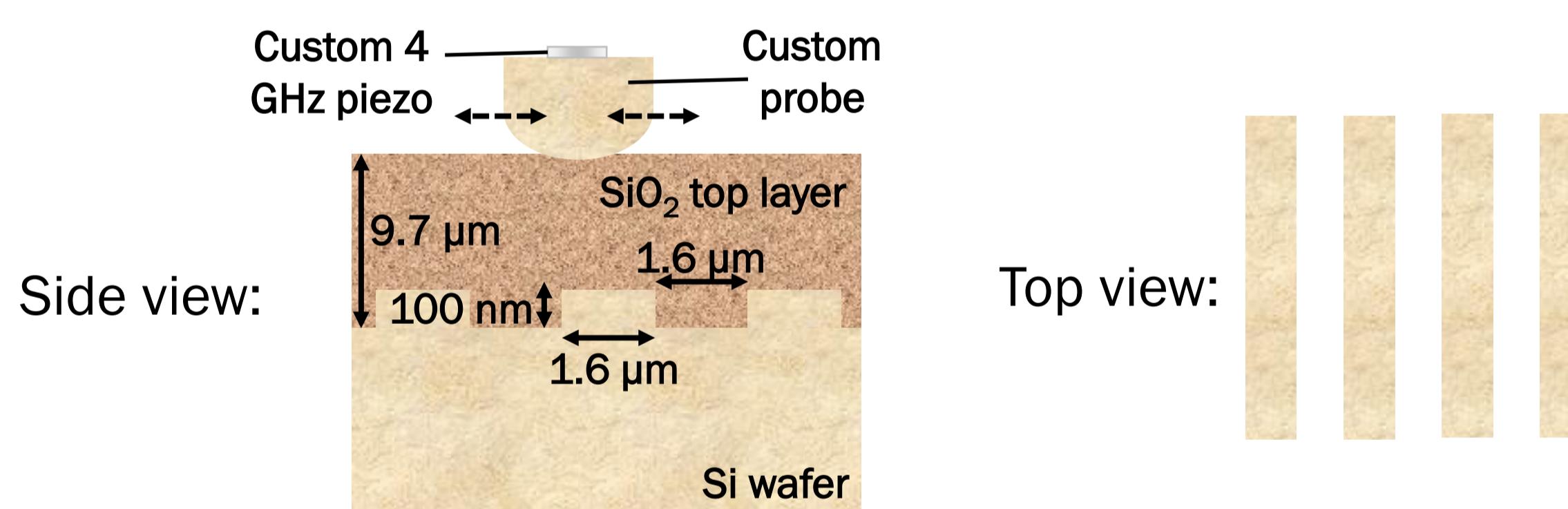
HaWaCAM characteristics:

- No coupling layer (contact mode)
- Frequency $>> 1 \text{ GHz} \rightarrow$ not limited by attenuation in coupling layer
- Currently implemented: 4 GHz – wavelength 0.75 μm in PMMA, 1.5 μm in SiO₂
- Penetration $O(10s \text{ of } \mu\text{m})$
- Non-destructive/nondamaging
- Ability to image through opaque layers

III. Custom GHz probe



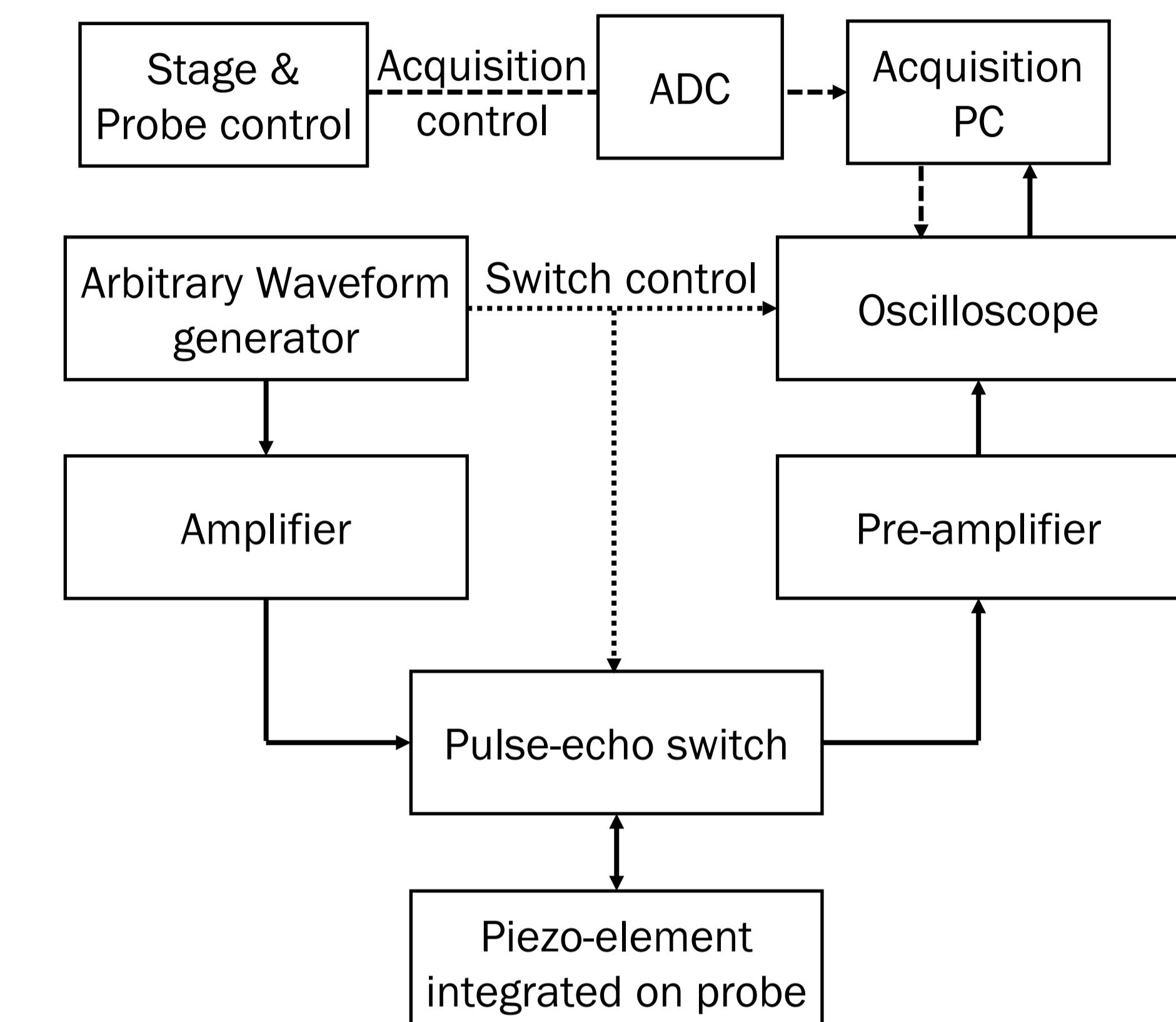
V. Experimental results: linear grating buried below 9.7 μm SiO₂



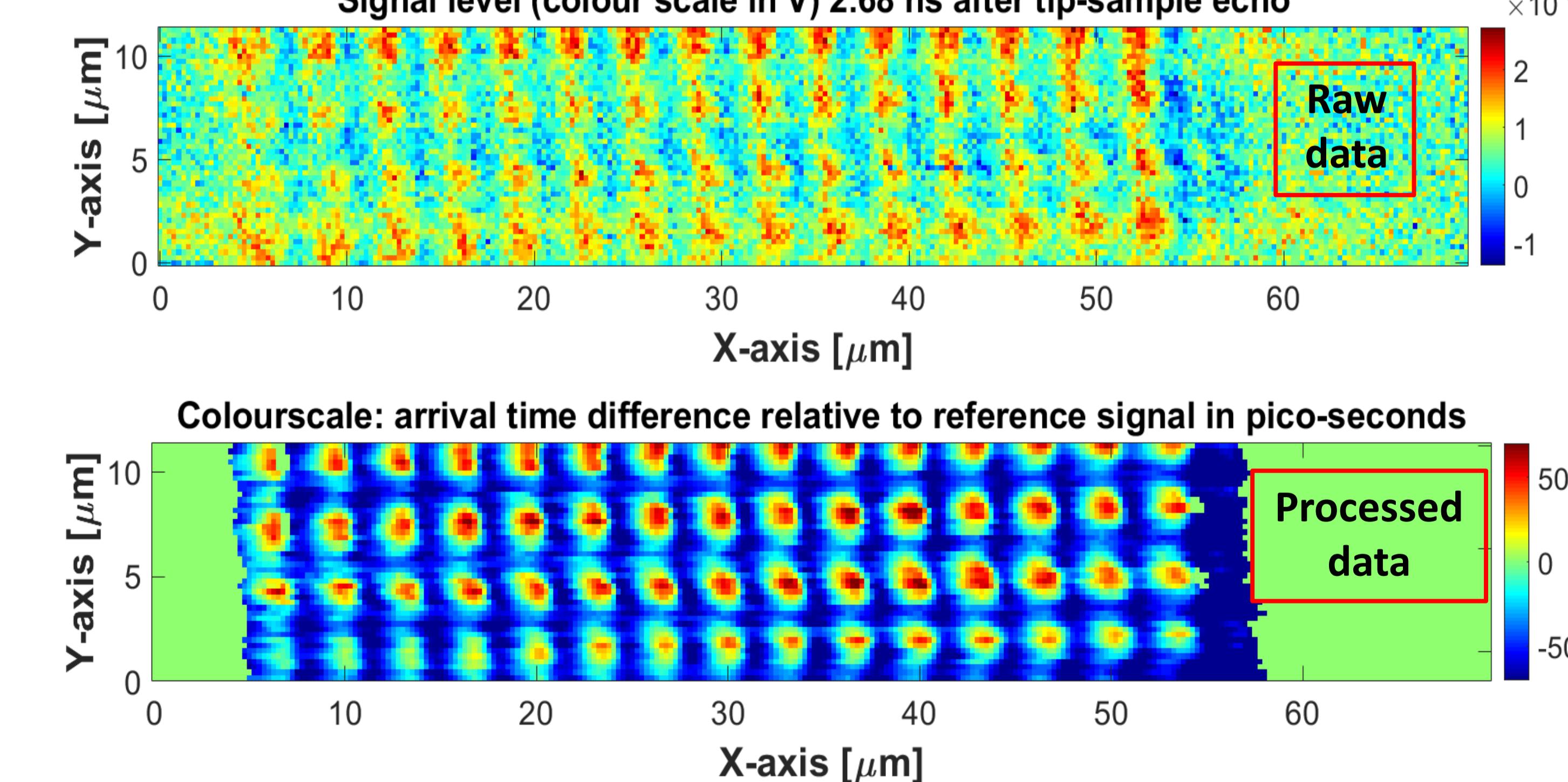
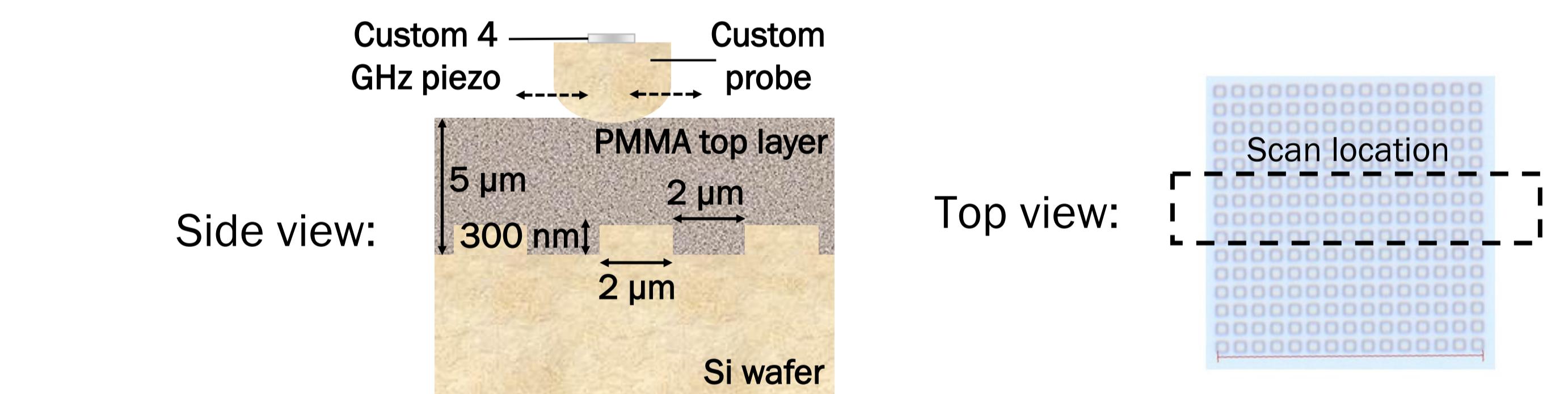
References

[1] Weiss, Lemor et al., IEEE Trans. Ultrason. Ferroelectr. Freq. Contr., 54(11), 2257-2271 (2007).

IV. Experimental setup



VI. Experimental results: matrix grating buried below 5 μm PMMA



VII. Discussion/Conclusion

- A novel high frequency acoustic metrology technique entitled Half-Wavelength Contact Acoustic Microscopy (HaWaCAM) was presented
- Current center frequency: 4 GHz, wavelength: 0.75 μm (PMMA), 1.5 μm (SiO₂)
- Picosecond arrival time accuracy
- Current acoustic measurement time/point: 0.4 ms